NSN 5961-01-379-4685

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View Online at https://aerobasegroup.com/nsn/5961-01-379-4685 **Inclosure Material:** Plastic **Overall Length:** Between 0.110 inches and 0.120 inches **Overall Height:** Between 0.030 inches and 0.047 inches Overall Width: Between 0.083 inches and 0.098 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -50.0 collector to emitter voltage, dc with base short-circuited to emitter and -45.0 collector to emitter voltage/static/base open and -5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** -500.00 milliamperes source cutoff current and -100.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 350.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 beam lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: